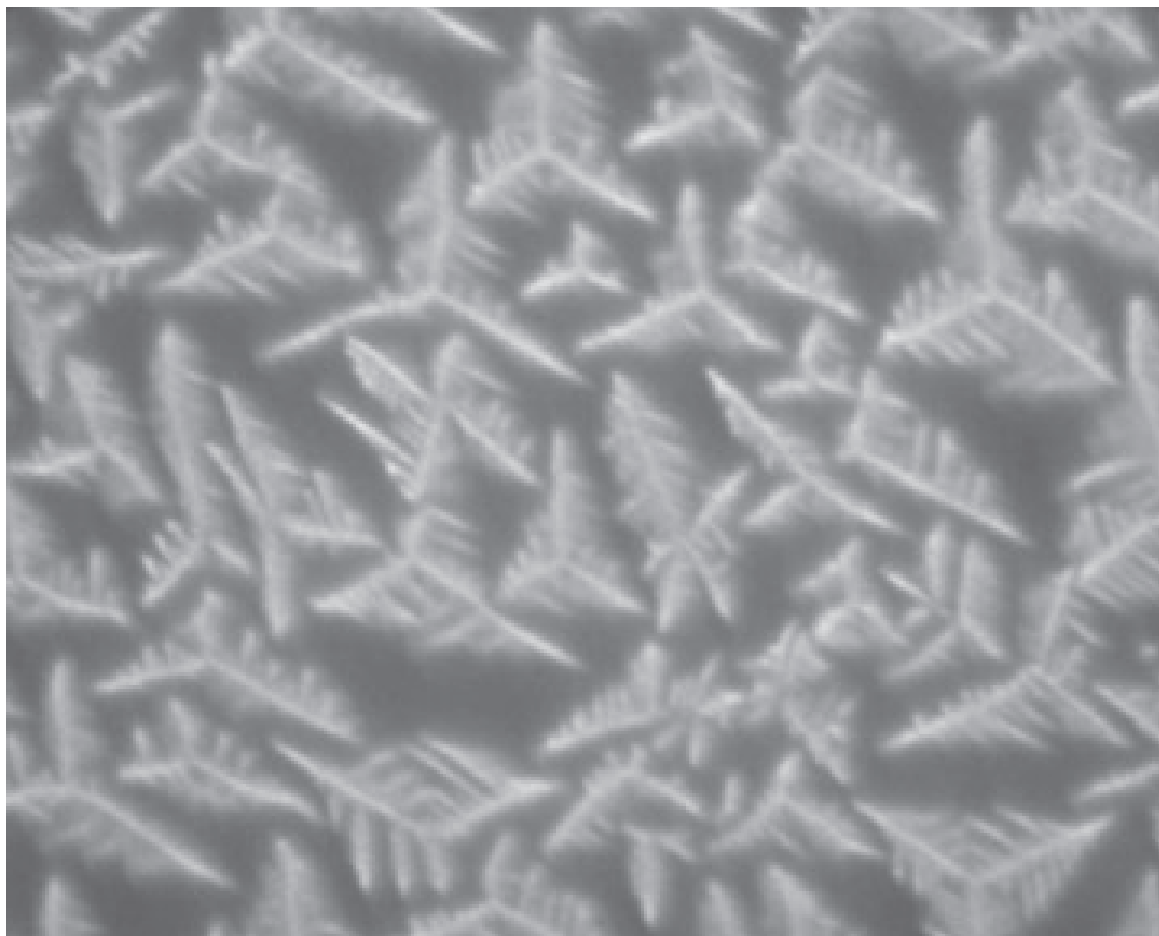




Different growth modes of molecular adsorbate systems and 2D materials investigated by low-energy electron microscopy

Janina Elisabeth Felter

Schlüsseltechnologien / Key Technologies

Band / Volume 206

ISBN 978-3-95806-434-8

Forschungszentrum Jülich GmbH
Peter Grünberg Institut (PGI)
Functional Nanostructures at Surfaces (PGI-3)

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Schriften des Forschungszentrums Jülich
Reihe Schlüsseltechnologien / Key Technologies

Band / Volume 206

ISSN 1866-1807

ISBN 978-3-95806-434-8

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